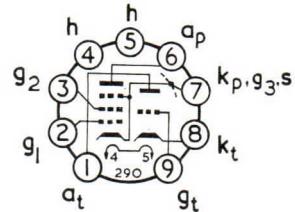


TIME BASE TRIODE PENTODE



B9A Base

GENERAL

This triode pentode is for use in line oscillator circuits with the pentode section as an oscillator and the triode section as a reactance valve.

Heater Current	I _h	0.3	A
Heater Voltage	V _h	9.0	V

DESIGN CENTRE RATINGS

	Triode	Pentode	
Maximum Anode Dissipation	Pa(max)	1.4	W
Maximum Screen Grid Dissipation	P _{g2} (max)	—	0.8 W
Maximum Anode Supply Voltage	V _{a(b)} max	550	V
Maximum Anode Voltage	V _a (max)	250	V
Maximum Screen Grid Supply Voltage	V _{g2(b)} max	—	V
Maximum Screen Grid Voltage	V _{g2} (max)	—	V
Maximum Heater to Cathode Voltage	V _{h-k} (max)	100†	V
Maximum Cathode Current	I _k (max)	10	mA
Maximum Peak Cathode Current	I _{k(pk)} max	—	mA
Maximum Grid to Cathode Resistance	R _{g-k} (max)	50*	mA
Fixed Bias		3.0	MΩ

* Maximum Duty Factor 30 per cent, maximum pulse duration 30 μs.

† To avoid hum interference the A.C. component should not exceed 65 V at Z_g(max) = 50 kΩ (f=50 c/s)

INTER-ELECTRODE CAPACITANCES

	Triode	Pentode	
Input	C _{in}	2.4	pF
Anode to Grid 1	C _{a-g₁}	1.5	pF
Grid 1 to Heater	C _{g₁-h}	<0.1	pF

CHARACTERISTICS

	Triode	Pentode	
Anode Voltage	V _a	200	V
Screen Grid Voltage	V _{g₂}	—	V
Control Grid Voltage	V _{g₁}	-2.0	V
Anode Current	I _a	3.5	mA
Screen Grid Current	I _{g₂}	—	mA
Mutual Conductance	g _m	3.5	mA/V
Valve Anode Resistance ($\delta V_a / \delta I_a$)	r _a	20	kΩ
Amplification Factor	μ	70	—
Inner Amplification Factor	μ _{g₁-g₂}	—	47
Anode Current at V _{g₁} = 0 V		—	12.5 mA
Screen Grid Current at V _{g₁} = 0 V		—	3.5 mA
Anode Current at I _g = + 10 μA, V _a = 200 V	10	—	mA
Negative Grid Voltage at V _a = V _{g₂} = 200 V, I _a = 10 μA	—	<16	V
Negative Grid Voltage at I _g = + 0.3 μA	<1.3	<1.3	V

